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January 2008

# 74LVTH125 Low Voltage Quad Buffer with 3-STATE Outputs

#### **Features**

- Input and output interface capability to systems at 5V V<sub>CC</sub>
- Bushold data inputs eliminate the need for external pull-up resistors to hold unused inputs
- Live insertion/extraction permitted
- Power Up/Down high impedance provides glitch-free bus loading
- Outputs source/sink -32mA/+64mA
- Functionally compatible with the 74 series 125
- Latch-up performance exceeds 500mA
- ESD performance:
  - Human-body model > 2000V
  - Machine model > 200V
  - Charged-device model > 1000V

## **General Description**

The LVTH125 contains four independent non-inverting buffers with 3-STATE outputs.

These buffers are designed for low-voltage (3.3V)  $V_{CC}$  applications, but with the capability to provide a TTL interface to a 5V environment. The LVTH125 is fabricated with an advanced BiCMOS technology to achieve high speed operation similar to 5V ABT while maintaining a low power dissipation.

## **Ordering Information**

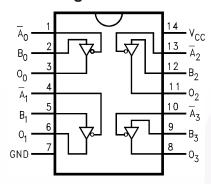
Order Number	Package Number	Package Description
74LVTH125M	M14A	14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow
74LVTH125SJ	M14D	14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide
74LVTH125MTC	MTC14	14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.



All packages are lead free per JEDEC: J-STD-020B standard.

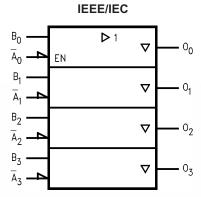
## **Connection Diagram**



## **Pin Description**

Pin Names	Description
$\overline{A}_n$ , $B_n$	Inputs
O <sub>n</sub>	3-STATE Outputs

## **Logic Symbol**



## **Truth Table**

Inp	Output	
Ā <sub>n</sub>	B <sub>n</sub>	O <sub>n</sub>
L	L	L
L	Н	Н
Н	X	Z

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial

Z = HIGH Impedance

## **Absolute Maximum Ratings**

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

Symbol	Parameter	Rating		
V <sub>CC</sub>	Supply Voltage	-0.5V to +4.6V		
V <sub>I</sub>	DC Input Voltage	-0.5V to +7.0V		
Vo	DC Output Voltage			
	Output in 3-STATE	-0.5V to +7.0V		
	Output in HIGH or LOW State <sup>(1)</sup>	-0.5V to +7.0V		
I <sub>IK</sub>	DC Input Diode Current, V <sub>I</sub> < GND			
I <sub>OK</sub>	DC Output Diode Current, V <sub>O</sub> < GND			
Io	DC Output Current, V <sub>O</sub> > V <sub>CC</sub>			
	Output at HIGH State	64mA		
	Output at LOW State	128mA		
I <sub>CC</sub>	DC Supply Current per Supply Pin	±64mA		
I <sub>GND</sub>	DC Ground Current per Ground Pin	±128mA		
T <sub>STG</sub>	Storage Temperature	−65°C to +150°C		

#### Note:

1. IO Absolute Maximum Rating must be observed.

## **Recommended Operating Conditions**

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

Symbol	Parameter	Min	Max	Units
V <sub>CC</sub>	Supply Voltage	2.7	3.6	V
VI	Input Voltage	0	5.5	V
I <sub>OH</sub>	HIGH-Level Output Current		-32	mA
I <sub>OL</sub>	LOW-Level Output Current		64	mA
T <sub>A</sub>	Free-Air Operating Temperature	-40	85	°C
Δt / ΔV	Input Edge Rate, $V_{IN} = 0.8V-2.0V$ , $V_{CC} = 3.0V$	0	10	ns/V

### **DC Electrical Characteristics**

					T <sub>A</sub> = -4	0°C to +	85°C	
	Parameter				Min.	Typ. <sup>(2)</sup>	Max.	1
Symbol			V <sub>CC</sub> (V) Conditions					Units
V <sub>IK</sub>	Input Clamp Diode Voltage		2.7	$I_I = -18\text{mA}$			-1.2	V
V <sub>IH</sub>	Input HIGH Voltage	Э	2.7-3.6	$V_0 \le 0.1V$ or	2.0			V
V <sub>IL</sub>	Input LOW Voltage	,	2.7-3.6	$V_O \ge V_{CC} - 0.1V$			0.8	V
V <sub>OH</sub>	Output HIGH Volta	ge	2.7–3.6	$I_{OH} = -100\mu A$	V <sub>CC</sub> - 0.2			V
			2.7	$I_{OH} = -8mA$	2.4			
			3.0	$I_{OH} = -32mA$	2.0			
V <sub>OL</sub>	Output LOW Voltag	ge	2.7	$I_{OL} = 100 \mu A$			0.2	V
				I <sub>OL</sub> = 24mA			0.5	
			3.0	I <sub>OL</sub> = 16mA			0.4	
				I <sub>OL</sub> = 32mA			0.5	
				I <sub>OL</sub> = 64mA			0.55	
I <sub>I(HOLD)</sub>	Bushold Input Mini	mum Drive	3.0	$V_{I} = 0.8V$	75			μA
	9			V <sub>I</sub> = 2.0V	-75			]
I <sub>I(OD)</sub>	Bushold Input Ove	r-Drive	3.0	(3)	500			μA
	Current to Change	State		(4)	-500			
I <sub>I</sub>	Input Current		3.6	V <sub>I</sub> = 5.5V			10	μA
		Control Pins	3.6	$V_I = 0V \text{ or } V_{CC}$			±1	=
		Data Pins	3.6	$V_I = 0V$			<b>-</b> 5	
				$V_I = V_{CC}$			1	
I <sub>OFF</sub>	Power Off Leakage	e Current	0	$0V \le V_I \text{ or } V_O \le 5.5V$			±100	μA
I <sub>PU/PD</sub>	Power up/down 3-9	STATE	0-1.5	$V_{O} = 0.5V$ to 3.0V,			±100	μA
	Output Current			$V_I = GND \text{ or } V_{CC}$				
$I_{OZL}$	3-STATE Output Le	eakage Current	3.6	$V_{O} = 0.5V$			-5	μA
$I_{OZH}$	3-STATE Output Le	eakage Current	3.6	$V_0 = 3.0V$			5	μΑ
I <sub>OZH</sub> +	3-STATE Output Le	eakage Current	3.6	$V_{CC} < V_O \le 5.5V$			10	μA
I <sub>CCH</sub>	Power Supply Curr	rent	3.6	Outputs HIGH			0.19	mA
I <sub>CCL</sub>	Power Supply Curr	rent	3.6	Outputs LOW			5	mA
I <sub>CCZ</sub>	Power Supply Curr	ent	3.6	Outputs Disabled			0.19	mA
I <sub>CCZ</sub> +	Power Supply Curr	ent	3.6	$V_{CC} \le V_O \le 5.5V$ , Outputs Disabled			0.19	mA
Δl <sub>CC</sub>	Increase in Power Supply Current <sup>(5)</sup>		3.6	One Input at V <sub>CC</sub> – 0.6V, Other Inputs at V <sub>CC</sub> or GND			0.2	mA

#### Notes:

- 2. All typical values are at  $V_{CC} = 3.3V$ ,  $T_A = 25$ °C.
- 3. An external driver must source at least the specified current to switch from LOW-to-HIGH.
- 4. An external driver must sink at least the specified current to switch from HIGH-to-LOW.
- 5. This is the increase in supply current for each input that is at the specified voltage level rather than  $V_{CC}$  or GND.

## **Dynamic Switching Characteristics(6)**

			Conditions	-	Γ <sub>A</sub> = 25°C	;	
Symbol	Parameter	V <sub>CC</sub> (V)	$C_L = 50 \text{ pF, } R_L = 500\Omega$	Min.	Тур.	Max.	Units
V <sub>OLP</sub>	Quiet Output Maximum Dynamic V <sub>OL</sub>	3.3	(7)		0.8		V
V <sub>OLV</sub>	Quiet Output Minimum Dynamic V <sub>OL</sub>	3.3	(7)		-0.8		V

#### Notes:

- 6. Characterized in SOIC package. Guaranteed parameter, but not tested.
- 7. Max number of outputs defined as (n). n-1 data inputs are driven 0V to 3V. Output under test held LOW.

### **AC Electrical Characteristics**

				0°C to +8			
		Vcc	$= 3.3V \pm 0$	).3V	V <sub>CC</sub> =	= 2.7V	
Symbol	Parameter	Min.	Typ. <sup>(8)</sup>	Max.	Min.	Max.	Units
t <sub>PLH</sub>	Propagation Delay, Data to Output	1.0		3.5	1.0	4.5	ns
t <sub>PHL</sub>		1.0		3.9	1.0	4.9	
t <sub>PZH</sub>	Output Enable Time	1.0		4.0	1.0	5.5	ns
t <sub>PZL</sub>		1.1		4.0	1.1	5.4	
t <sub>PHZ</sub>	Output Disable Time	1.5		4.5	1.5	5.7	ns
t <sub>PLZ</sub>		1.3		4.5	1.3	4.0	
t <sub>OSHL</sub> , t <sub>OSLH</sub>	Output to Output Skew <sup>(9)</sup>			1.0		1.0	ns

#### Notes:

- 8. All typical values are at  $V_{CC} = 3.3V$ ,  $T_A = 25$ °C.
- 9. Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t<sub>OSHL</sub>) or LOW-to-HIGH (t<sub>OSLH</sub>).

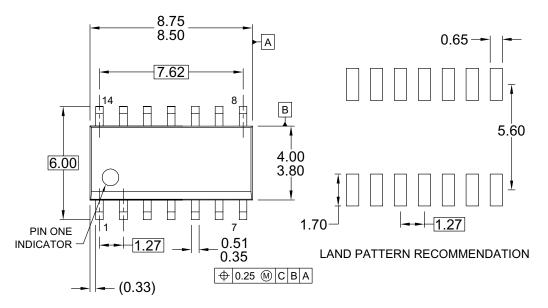
## Capacitance<sup>(10)</sup>

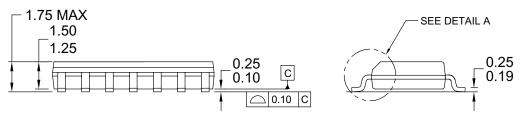
Symbol	Parameter	Conditions	Typical	Units
C <sub>IN</sub>	Input Capacitance	$V_{CC} = 0V$ , $V_I = 0V$ or $V_{CC}$	4	pF
C <sub>OUT</sub>	Output Capacitance	$V_{CC} = 3.0V$ , $V_{O} = 0V$ or $V_{CC}$	8	pF

#### Note:

10. Capacitance is measured at frequency f = 1MHz, per MIL-STD-883B, Method 3012.

## **Physical Dimensions**





NOTES: UNLESS OTHERWISE SPECIFIED

R0.10

R0.10

GAGE PLANE

0.36

0.90

DETAIL A

- A) THIS PACKAGE CONFORMS TO JEDEC MS-012, VARIATION AB, ISSUE C,
- B) ALL DIMENSIONS ARE IN MILLIMETERS.
- C) DIMENSIONS DO NOT INCLUDE MOLD FLASH OR BURRS.
- D) LANDPATTERN STANDARD: SOIC127P600X145-14M
- E) DRAWING CONFORMS TO ASME Y14.5M-1994
- F) DRAWING FILE NAME: M14AREV13

Figure 1. 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow

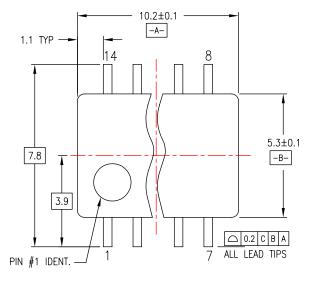
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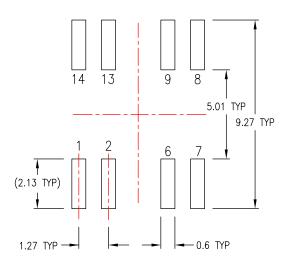
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SEATING PLANE

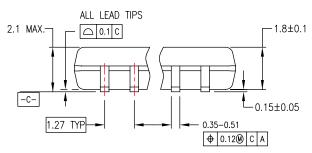
0.50 (1.04)

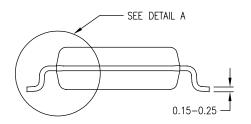
## Physical Dimensions (Continued)





#### LAND PATTERN RECOMMENDATION



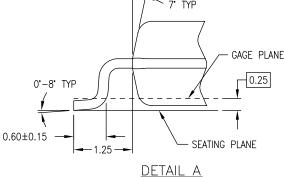


DIMENSIONS ARE IN MILLIMETERS

NOTES:

- A. CONFORMS TO EIAJ EDR-7320 REGISTRATION, ESTABLISHED IN DECEMBER, 1998.
  B. DIMENSIONS ARE IN MILLIMETERS.

- DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS.



M14DREVC

Figure 2. 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide

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#### Physical Dimensions (Continued) 5.0±0.1 -A-0.43 TYF 0.65 6.4 4.4±0.1 -B--1.65 3.2 □ 0.2 C B A PIN #1 IDENT. 6 10 LAND PATTERN RECOMMENDATION SEE DETAIL A ALL LEAD TIPS 0.90+0.15 1.2 MAX □ 0.1 C -0.10 0.09-0.20 -C-0.10±0.05 0.65 0.19 - 0.30⊕ 0.13M ABS CS 12.00°TOP & BOTTOM R0.09 min **GAGE PLANE** 0.25 0°-8° NOTES: A. CONFORMS TO JEDEC REGISTRATION MO-153. 0.6±0.1 SEATING PLANE R0.09min VARIATION AB, REF NOTE 6 1 00 **B. DIMENSIONS ARE IN MILLIMETERS** DETAIL A

- C. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH, AND TIE BAR EXTRUSIONS
- D. DIMENSIONING AND TOLERANCES PER ANSI Y14.5M, 1982
- E. LANDPATTERN STANDARD: SOP65P640X110-14M
- F. DRAWING FILE NAME: MTC14REV6

Figure 3. 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide

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